

描述 / Descriptions

TO-220 塑封封装 双向可控硅。Triac in a TO-220 Plastic Package.

特征 / Features

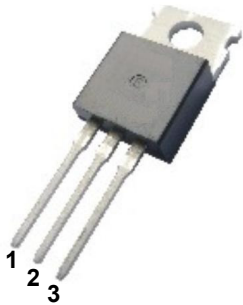
中电流可控硅，低通态压降，高可靠性和稳定性，热敏电阻特性低，高转换性能。

Medium current triac, Low on state voltage drop, High reliability and stability, Low thermal resistance, High commutation performances.

用途 / Applications

适用于一般用途交流开关。如固态继电器、加热调节、异步电动机起动电路、电机速度控制器等。

Suitable for general purpose AC switching .Such as static relays, heating regulation, induction motor starting circuits, motor speed controllers etc.

内部等效电路 / Equivalent Circuit**引脚排列 / Pinning**

PIN1 : Main Terminal 1 PIN 2 : Main Terminal 2 PIN 3: Gate

放大及印章代码 / h_{FE} Classifications & Marking

见印章说明。See Marking Instructions.

极限参数 / Absolute Maximum Ratings(Ta=25°C)

参数 Parameter	符号 Symbol	数值 Rating	单位 Unit
Repetitive peak off-state voltages	$V_{\text{DRM}}/V_{\text{RRM}}$	600/800	V
On-state rms current(full sine wave $T_C=105^\circ\text{C}$)	$I_{\text{T(RMS)}}$	10	A
Non repetitive surge peak on-state current(full cycle, T_j initial= 25°C)	$I_{\text{TSM}}(F=50\text{Hz}$ $t=20\text{ms})$	100	A
Non repetitive surge peak on-state current(full cycle, T_j initial= 25°C)	$I_{\text{TSM}}(F=60\text{Hz}$ $t=16.7\text{ms})$	105	A
I^2_t value for fusing	$I^2_{\text{t}}(t_p=10\text{ms})$	55	A^2s
Critical rate of rise of on-state current $I_G=2\times I_{\text{GT}}$, $t_r\leq 100\text{ ns}$ ($F=120\text{Hz}$ $T_j=125^\circ\text{C}$)	di/dt	50	$\text{A}/\mu\text{s}$
Peak gate current($t_p=20\mu\text{s}$ $T_j=125^\circ\text{C}$)	I_{GM}	4.0	A
Average gate power dissipation($T_j=125^\circ\text{C}$)	$P_{\text{G(AV)}}$	1.0	W
Operating junction temperature range	T_j	$-40\sim+125$	$^\circ\text{C}$
Storage junction temperature range	T_{stg}	$-40\sim+150$	$^\circ\text{C}$
Junction to ambient	$R_{\text{th(j-a)}}$	60	$^\circ\text{C}/\text{W}$
Junction to case for AC	$R_{\text{th(j-c)}}$	1.5	

电性能参数 / Electrical Characteristics(Ta=25°C)
免缓冲器和逻辑电平 (3象限) / Snubberless and logic level (3 quadrants)

符号 Symbol	测试条件 Test Conditions		信号区 Quadrant		BTB10		单位 Unit
					CW	BW	
$I_{\text{GT}}^{(1)}$	$V_D=12\text{V}$	$R_L=33\Omega$	I-II-III	Max.	35	50	mA
V_{GT}	$V_D=12\text{V}$	$R_L=33\Omega$	I-II-III	Max.	1.3		V
V_{GD}	$V_D=V_{\text{DRM}}$ $T_j=125^\circ\text{C}$	$R_L=3.3\text{K}\Omega$	I-II-III	Min.	0.2		V
$I_{\text{H}}^{(2)}$	$I_T=500\text{mA}$			Max.	35	50	mA
I_{L}	$I_G=1.2I_{\text{GT}}$	I-III	Max.		50	70	mA
		II			60	80	
$(dV/dt)^{(2)}$	$V_D=67\% V_{\text{DRM}}$ gate open		$T_j=125^\circ\text{C}$	Min.	500	1000	$\text{V}/\mu\text{s}$
$(di/dt)^{(2)}$	Without snubber		$T_j=125^\circ\text{C}$	Min.	5.5	9.0	A/ms

电性能参数 / Electrical Characteristics(Ta=25°C)

标准 (4象限) / Standard (4 quadrants)

符号 Symbol	测试条件 Test Conditions	信号区 Quadrant		BTB10		单位 Unit
				C	B	
$I_{GT}^{(1)}$	$V_D=12V$ $R_L=33\Omega$	I-II-III IV	Max.	25 50	50 100	mA
V_{GT}	$V_D=12V$ $R_L=33\Omega$	ALL	Max.	1.3		V
V_{GD}	$V_D=V_{DRM}$ $R_L=3.3K\Omega$ $T_j=125^\circ C$	ALL	Min.	0.2		V
$I_H^{(2)}$	$I_T=500mA$		Max.	25	50	mA
I_L	$I_G=1.2I_{GT}$	I-III- IV	Max.	40	50	mA
		II		80	100	
$(dV/dt)^{(2)}$	$V_D=67\% V_{DRM}$ gate open $T_j=125^\circ C$		Min.	200	400	V/ μs
$(dV/dt)c^{(2)}$	$(dI/dt)c=4.4A/ms$ $T_j=125^\circ C$		Min.	5.0	10	

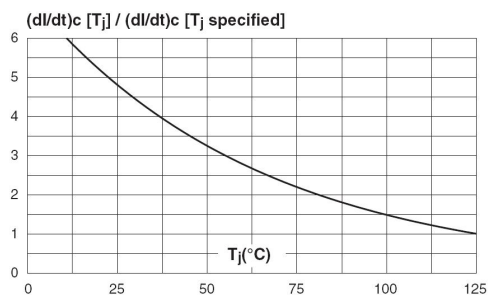
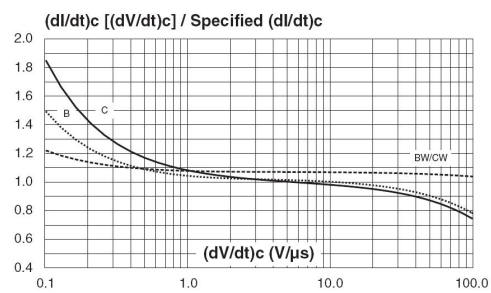
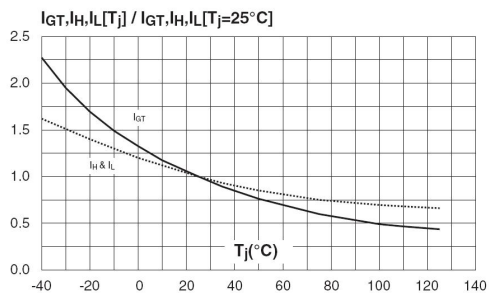
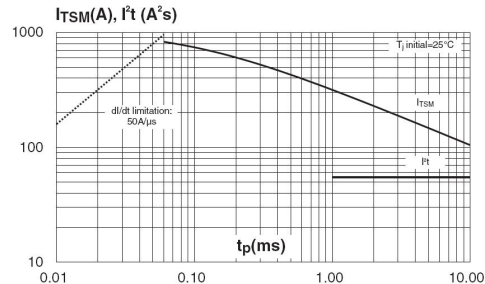
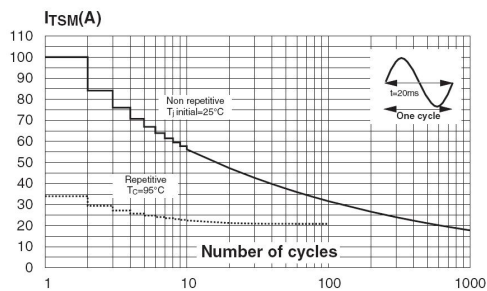
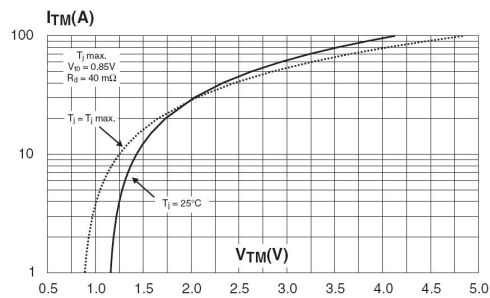
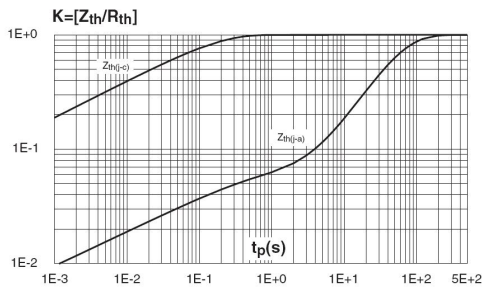
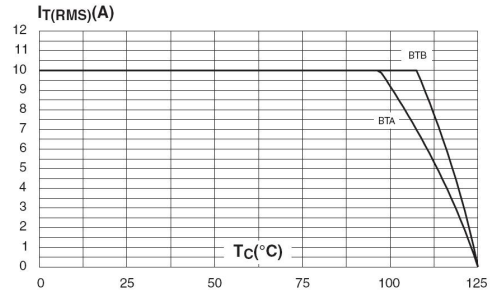
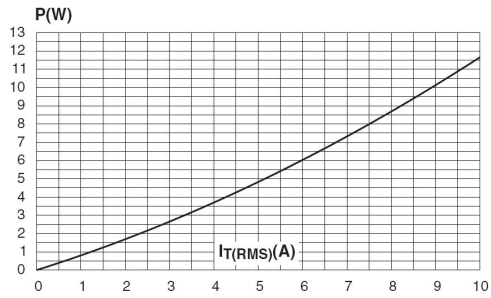
电性能参数 / Electrical Characteristics(Ta=25°C)

符号 Symbol	测试条件 Test Conditions			数值 Value	单位 Unit	
$V_T^{(2)}$	$I_{TM}=14A$	$t_p=380\mu s$	$T_J=25^{\circ}C$	Max.	1.55	V
$V_{to}^{(2)}$	Threshold voltage $T_J=125^{\circ}C$			Max.	0.85	V
$R_d^{(2)}$	Dynamic resistance $T_J=125^{\circ}C$			Max.	40	mΩ
I_{DRM} I_{RRM}	$V_{DRM}=V_{RRM}$	$T_J=25^{\circ}C$	Max.	5.0	μA	
		$T_J=125^{\circ}C$	Max.	1.0	mA	

Note 1: minimum I_{GT} is guaranteed at 5% of I_{GT} max.

Note 2: for both polarities of A2 referenced to A1.

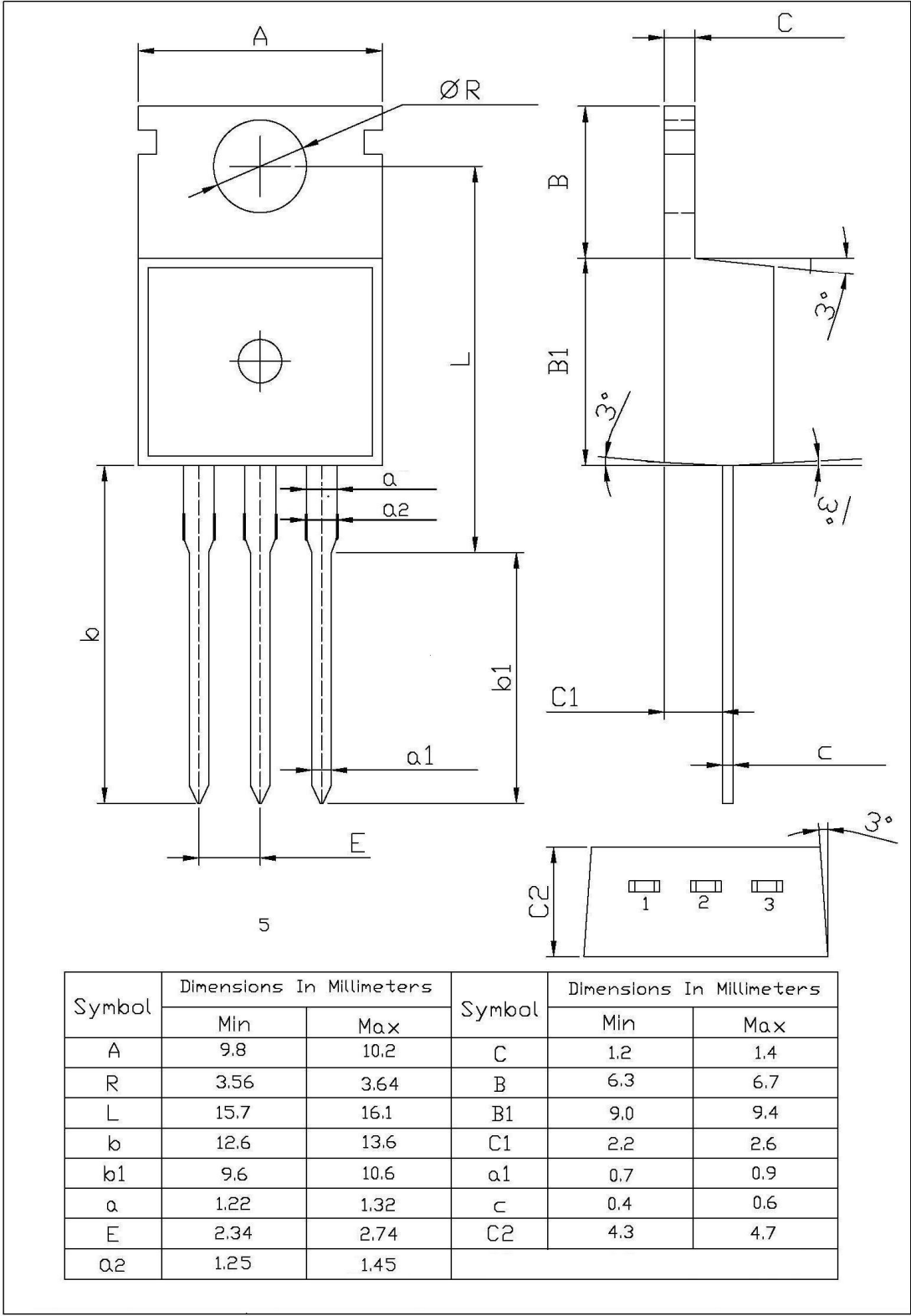
电参数曲线图 / Electrical Characteristic Curve

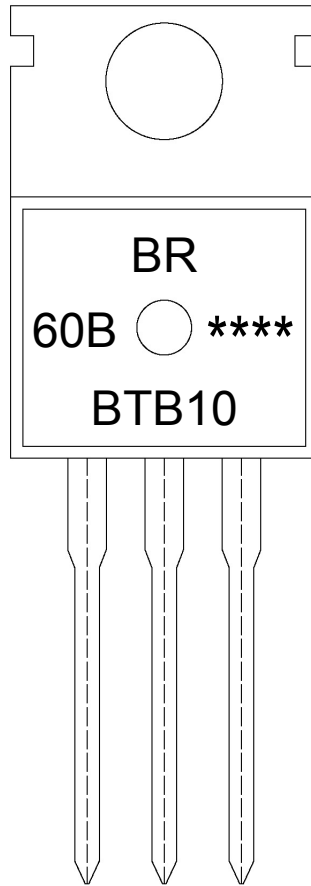


外形尺寸图 / Package Dimensions

T□-220

单位: mm



印章说明 / Marking Instructions

说明：

BR： 为公司代码

BTB10： 为产品型号

60B： 为 V_{RRM} 和 I_{GT} 分档代码

****： 为生产批号代码，随生产批号变化。

Note:

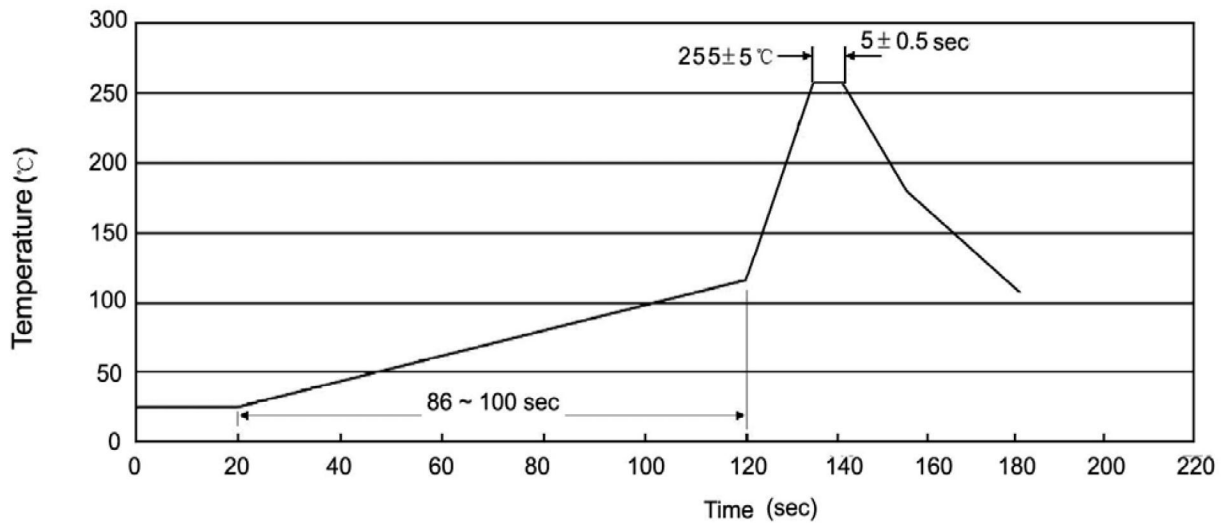
BR: Company Code

60B: V_{RRM}/I_{GT} Bracket code

BTB10: Product Type.

****: Lot No. Code, code change with Lot No.

波峰焊温度曲线图(无铅) / Temperature Profile for Dip Soldering(Pb-Free)



说明：

1. 预热温度 25 ~ 150°C，时间 60 ~ 90sec;
2. 峰值温度 255±5°C，时间持续为 5±0.5sec;
3. 焊接制程冷却速度为 2 ~ 10°C/sec.

Note:

1. Preheating: 25~150°C, Time: 60~90sec.
2. Peak Temp.: 255±5°C, Duration: 5±0.5sec.
3. Cooling Speed: 2~10°C/sec.

耐焊接热试验条件 / Resistance to Soldering Heat Test Conditions

温度：270±5°C

时间：10±1 sec.

Temp.: 270±5°C

Time: 10±1 sec

包装规格 / Packaging SPEC.

散件包装 / BULK

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Bag 只/袋	Bags/Inner Box 袋/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Bag 袋	Inner Box 盒	Outer Box 箱
TO-220/F	200	10	2,000	5	10,000	135×190	237×172×102	560×245×195

套管包装 / TUBE

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Tube 只/套管	Tubes/Inner Box 套管/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Tube 套管	Inner Box 盒	Outer Box 箱
TO-220/F	50	20	1,000	5	5,000	532×31.4×5.5	555×164×50	575×290×180

使用说明 / Notices